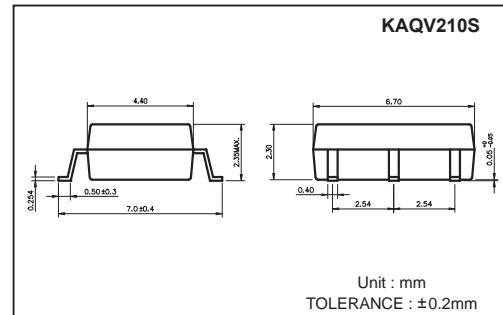


Features

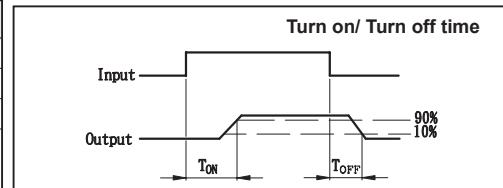
1. Normally Open, Single Pole Single Throw
2. Control 350VAC or DC Voltage
3. Switch 130mA Loads
4. LED control Current, 5mA
5. Low ON-Resistance
6. dv/dt, >500V/ms
7. Isolation Test Voltage, 1500VACrms



Absolute Maximum Ratings

(Ta=25°C)

Emitter (Input)	Detector (Output)
Reverse Voltage.....5.0V	Output Breakdown Voltage±350V
Continuous Forward Current50mA	Continuous Load Current±130mA
Peak Forward Current1A	Power Dissipation500mW
Power Dissipation100mW	
Derate Linearly from 25°C1.3mW/°C	
General Characteristics	
Isolation Test Voltage.....1500VACrms	Storage Temperature Range ...-40°C to +125°C
Isolation Resistance	Operating Temperature Range...-30°C to +85°C
Vio=500V, Ta=25°C $\geq 10^{10}\Omega$	Junction Temperature.....100°C
Total Power Dissipation550mW	Soldering Temperature,
Derate Linearly from 25°C2.5mW/°C	2mm from case, 10 sec260°C



Electro-optical Characteristics

(Ta=25°C)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit		
Emitter (Input)								
Forward Voltage	VF	IF=10mA		1.2	1.5	V		
Operation Input Current	IFON	VL =±20V, IL =100mA, t =10mS		5		mA		
Recovery Input Current	IOFF	VL =±20V, IL ≤5μA	0.2			mA		
Detector (Output)								
Output Breakdown Voltage	VB	IB=50μA	350			V		
Output Off-State Leakage	ITOFF	VT=100V, IF=0mA	0.2	1		uA		
I/O Capacitance	CISO	IF =0, f =1MHz	6			pF		
ON Resistance	Connection	RON	IL =100mA, IF =10mA	20	30	Ω		
				10	15			
				5	7.5			
Turn-On Time			IF =10mA, VL =±20V	0.3	1.0	ms		
Turn-Off Time			t =10ms, IL =±100mA	0.7	1.5	ms		

Mos Relay Schematic and Wiring Diagrams

Type	Schematic	Output configuration	Load	Connection	Wiring Diagrams
KAQV210S		1a	AC/DC	A	
			DC	C	

Data Curve

Fig.1 Load current vs. ambient temperature
Allowable ambient temperature:
-40°C to +85°C

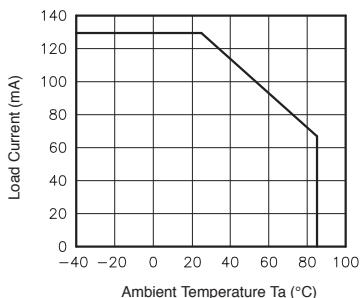


Fig.2 On resistance vs. ambient temperature
Across terminals 4 and 6 pin
LED current: 5mA
Continuous load current: 130mA(DC)

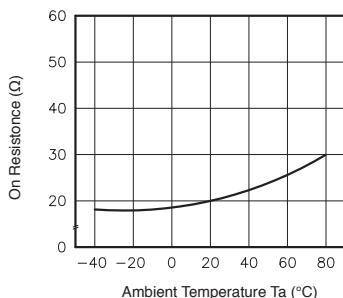


Fig.3 Turn on time vs. ambient temperature
Across terminals 4 and 6 pin
LED current: 5mA
Continuous load current: 130mA(DC)

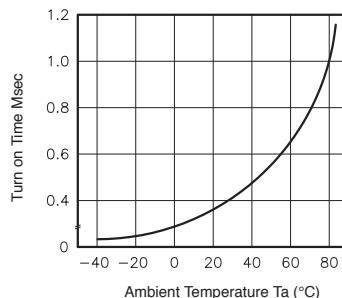


Fig.4 Turn off time vs. ambient temperature
LED current: 5mA; Load voltage:
350V(DC)
Continuous load current: 130mA(DC)

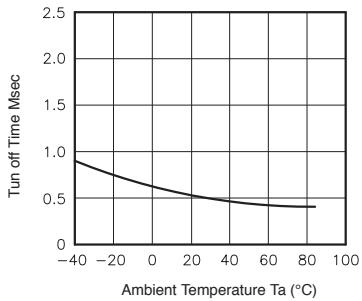


Fig.5 LED operate vs. ambient temperature
Load voltage 350V(DC)
Continuous load current: 130mA(DC)

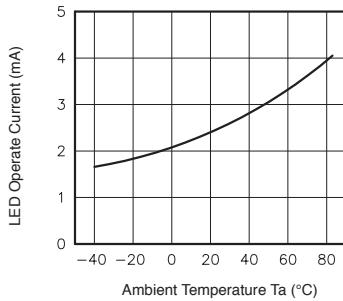


Fig.6 LED turn off current vs. ambient temperature
Load voltage 350V(DC)
Continuous load current: 130mA(DC)

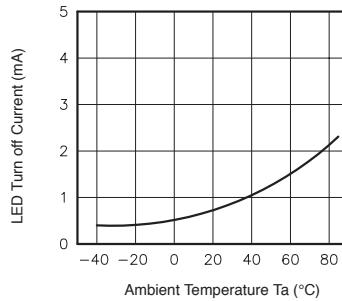


Fig.7 LED dropout voltage vs. ambient temperature
LED current: 5 to 50mA

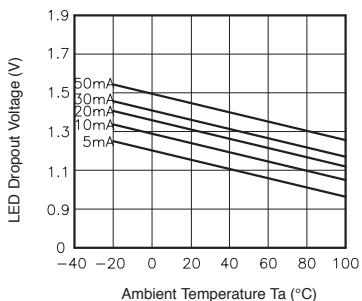


Fig.8 Voltage vs. current characteristics of output at MOS FET portion
Measured portion: across terminals 4 and 6 pin
Ambient temperature: 25°C

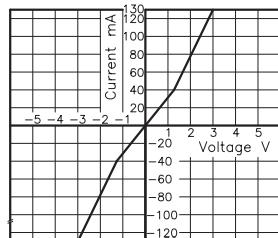


Fig.9 Off state leakage current
Across terminals 4 and 6 pin
Ambient temperature: 25°C

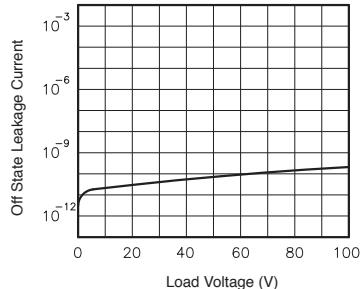


Fig.10 LED forward current vs. turn on time
Across terminals 4 and 6 pin;
Load voltage: 350V (DC);
Continuous load current: 130mA (DC);
Ambient temperature: 25°C

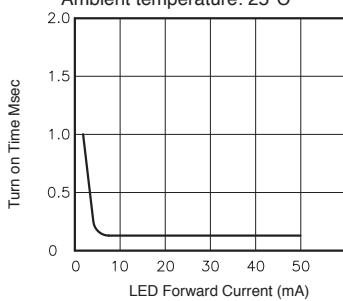


Fig.11 LED forward current vs. turn off time
Across terminals 4 and 6 pin;
Load voltage: 350V (DC);
Continuous load current: 130mA (DC);
Ambient temperature: 25°C

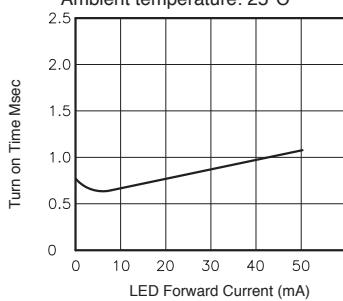


Fig.12 Applied voltage vs. output capacitance
Across terminals 4 and 6 pin
Frequency: 1MHz
Ambient temperature: 25°C

